.IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant(s):

Daniel L. Auclair, Jeffrey Craig, John S. Mangan, Robert D. Norman,

Daniel C. Guterman and Sanjay Mehrotra

Title:

Soft Errors Handling in EEprom Devices

Serial No.:

09/437,078

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San Francisco, California

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BOX AFTER FINAL COMMISSIONER FOR PATENTS Washington, D. C. 20231

MAY 1 5 2002 Technology Center 2100

AMENDMENT AFTER FINAL

Dear Sir:

Responsive to the Official Action mailed on February 12, 2002, setting a response period expiring on May 12, 2002, applicant responds to the Official Action as follows: 09437078 00000013 192386

05/14/2002 JADDO1 02 FC:102

84.00 CH In the Claims

Please add the following new claims:

--46.(New) A method of improving data retention in a nonvolatile writable memory having a first reference level and a second reference level, the nonvolatile writable memory having a plurality of memory cells organized into sectors, each of the memory cells being in an first state when storing a charge below the first reference level, and each of the memory cells being in a second state when storing a charge above the second reference level, the method comprising:

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accessing a first sector of said memory cells;

identifying a second sector of said memory cells having one or more memory cells with a charge above the first reference level and below the second reference level; and rewriting the data values stored in the memory cells of the second sector.

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